

**AMENDMENTS TO THE SPECIFICATION**

Please replace the following paragraphs of the specification. Applicants include herewith an Attachment for Specification Amendments showing a marked up version of each replacement paragraph.

**On page 9 of the specification, please replace the third paragraph with the following amended paragraph:**

Further, specific examples of the ferroelectric material include  $(Ba_{1-y}Sr_y)TiO_3$  (note that, y satisfies  $0 < y < 1$ ),  $PbTiO_3$ ,  $Pb-(Zr_{1-z}Ti_z)TiO_3$  (note that, z satisfies  $0 < z < 1$ ),  $BaTiO_3$ , and the like. Of the foregoing ferroelectric materials, it is more preferable to use  $Pb-(Zr, Ti)TiO_3$  in terms of ferroelectric polarization.

**On page 14 of the specification, please replace the third full paragraph with the following amended paragraph:**

It is more preferable to arrange the field-effect transistor of the present invention so that: the dielectric material or the ferroelectric material is  $BaTiO_3$ ,  $SrTiO_3$ ,  $(Ba_{1-y}Sr_y)TiO_3$ ,  $PbTiO_3$ ,  $Pb-(Zr_{1-z}Ti_z)TiO_3$ , or  $Al_2O_3$ , where y satisfies  $0 < y < 1$  and z satisfies  $0 < z < 1$ .